Exercise 9.2-1

Quick Questions to

9.2 - Optoelectronics - Important Principles and Technologies

Here are some quick questions

- Describe some measures necessary of you want to produce a high-efficiency LED. Use hand drawings to illustrate (at least) three major points.
- How can you best define a recombination volume?
- Draw the band diagram of an Np junction in equilibrium with the bandgap of the N-type semiconductor about twice the size of the p-type material. Discuss choice you make if necessary.
- Discuss advantages an problems of hetero junctions for light emitting devices
- Describe the working principle of MBE and what it means in terms of realization.
- Describe the mechanisms of *fundamental absorption* (FA) and *stimulated emission* (SE) with the aid of a band diagram. What kind of relation between the rates R_{Se} and R_{FA}, i.e. the number of events per second (and cm²) must you have if amplification of light is to take place?
- What is the meaning of "inversion" in the context of a semiconductor Laser?
- What is "pumping" in the context of a Laser and why is a semiconductor very well suited for efficient "pumping"?
- Bow can you turn a light amplifier into a Laser? What does it mean technically for processing your semiconductor?

Here is a somewhat "longer" question:

The picture shows a schematic "to scale" drawing of a simple blue Laser diode and the relevant material parameters in the "master" diagram.

- What kind of approximate band gap energy can you assign to the various layers? Draw a schematic band diagram of this kind of situation.
- Which layer is the light-producing one?
- What is the function of the three relatively thin layers in the center region?
- What could be the function of the two thicker pure GaN layers?
- Why is the whole structure on an Al₂O₃ substrate (= sapphire) and what is the *electrical* problem encountered?
- What might be the problem necessitating a "buffer" layer between the Al₂O₃ substrate and the stack of functional layers?
- Where are the mirrors necessary for a Laser?
- What is obviously used for n- or p-doping? Make a guess as to why the very thin central layer contains Mg and Si as dopants

